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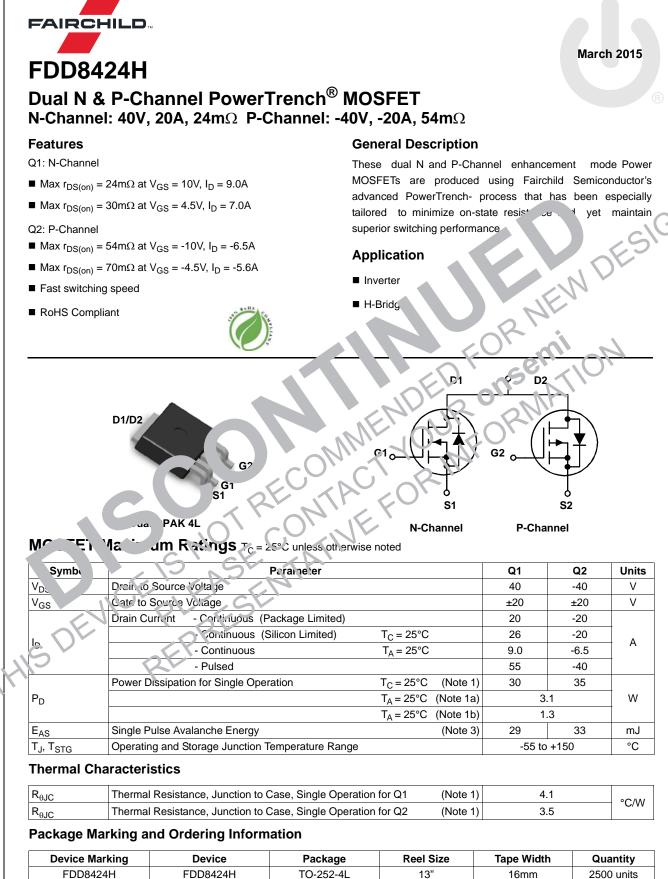
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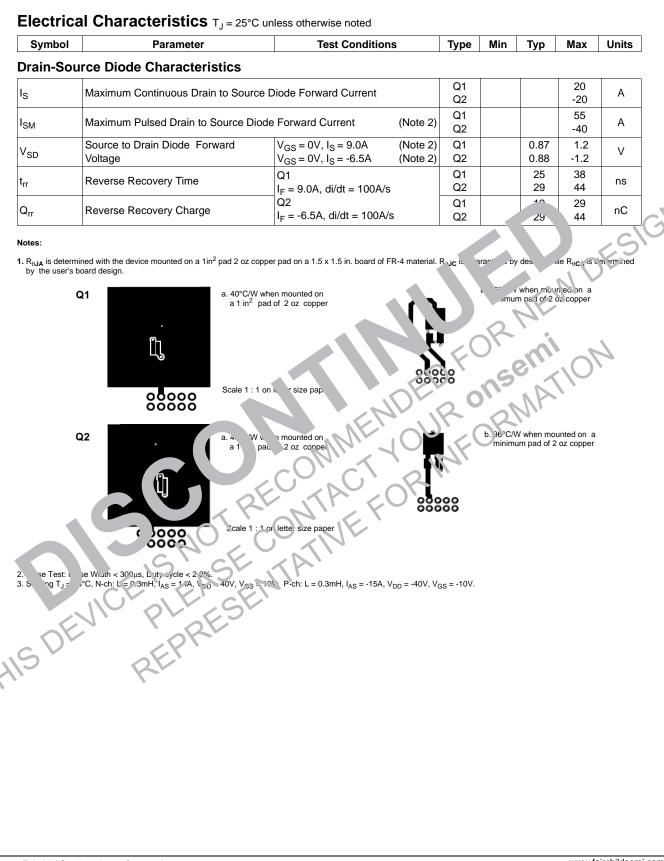
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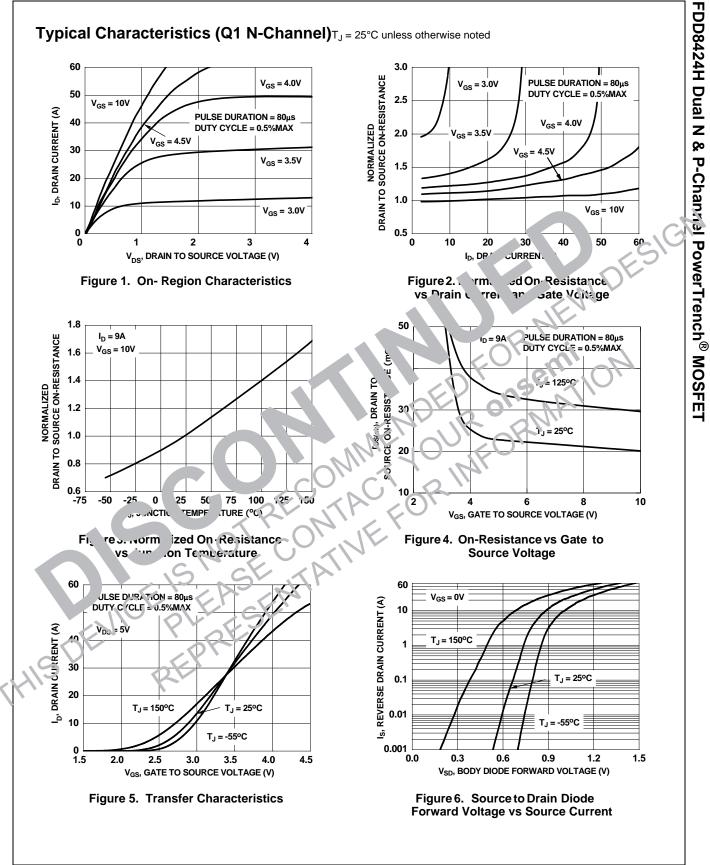


Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Un
Off Chara	acteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$ $I_D = -250 \mu A, V_{GS} = 0 V$	Q1 Q2	40 -40			\
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu$ A, referenced to 25°C $I_D = -250\mu$ A, referenced to 25°C	Q1 Q2		34 -32		mV
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 32V,  V_{GS} = 0V$ $V_{DS} = -32V,  V_{GS} = 0V$	Q1 Q2			1 -1	μ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	Q1 Q2			±100 ±100	n n
On Chara	acteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$ $V_{GS} = V_{DS}, I_D = -250\mu A$	Q1 Q2	-1	1.7	3 -3	1
$rac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu$ A, referenced to 25°C $I_D = -250 \mu$ A, referenced to 25°C	Q. Q2		-5 1.8		nıv
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 10V, I_D = 9.0A$ $V_{GS} = 4.5V, I_D = 7.0A$ $V_{GS} = 10V, I_D = 9.0A, T_J = 25^{\circ}$	٩		19 ?.` 2J	24 30 37	m
		$ \begin{array}{c} V_{GS} = -10V, \ I_{r} = - \\ V_{GS} = -4.5' \ i_{L} = -5. \\ V_{GS} = -4.5' \ i_{L} = -5. \\ \end{array} $	C2	DK.	42 58 (`2	54 70 გე	2
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 51$ , $D = 9.0$ $V_{DS} = -5V$ , $= -6.5A$	Q1 Q2	ns	29 13	10	
Dynamic	Characteristics		2	2	$h_{\mu}$		
C <sub>iss</sub>	Input Capacitance	$\overline{21}$ $v_{DS} = 20.7$ , $v_{GS} = 0V$ , $\hat{r} = 1MmZ$	01 Q2	D	750 1000	1000 1330	F
C <sub>oss</sub>	Output Capa ance		Q1 Q2		115 140	155 185	F
C <sub>rss</sub>	Rei Trai, ir Caplitance	$V_{DS} = -20V, V_{GS} = 0V, f = 1.4.4Z$	Q1 Q2		75 75	115 115	F
R <sub>g</sub>	Gate mesist ce	= MHz	Q1 Q2	0.1 0.1	1.1 3.3	3.3 9.9	9
vitchı.	C vracteristics	TAI					
t <sub>d(oi</sub>	Turn On Delay Tim	Q1	Q1 Q2		7 7	14 14	r
t <sub>r</sub>	Rise Time	$V_{DD} = 20V, I_D = 9.0A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$	Q1 Q2		13 3	24 10	1
ta(off)	Turn-Off Delay 7 in 🤕	Q2 V <sub>DD</sub> = -20V, I <sub>D</sub> = -6.5A,	Q1 Q2		17 20	31 36	r
ι <sub>f</sub>	Fall Time	$V_{GS} = -10V, R_{GEN} = 6\Omega$	Q1 Q2		6 3	12 10	1
Q <sub>g(TOT)</sub>	Total Gate Charge	Q1	Q1 Q2		14 17	20 24	r
Q <sub>gs</sub>	Gate to Source Charge	$-V_{GS} = 10V, V_{DD} = 20V, I_D = 9.0A$	Q1 Q2		2.3 3.0		r
Q <sub>gd</sub>	Gate to Drain "Miller" Charge	V <sub>GS</sub> = -10V, V <sub>DD</sub> = -20V, I <sub>D</sub> = -6.5A	Q1 Q2		3.2 3.6		r

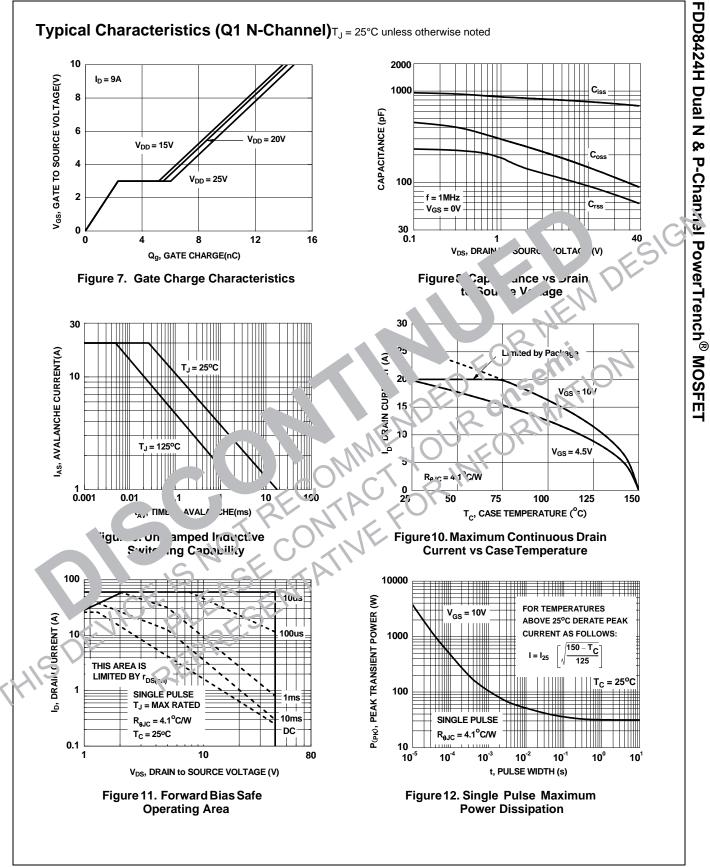
FDD8424H Dual N & P-Channel PowerTrench<sup>®</sup> MOSFET



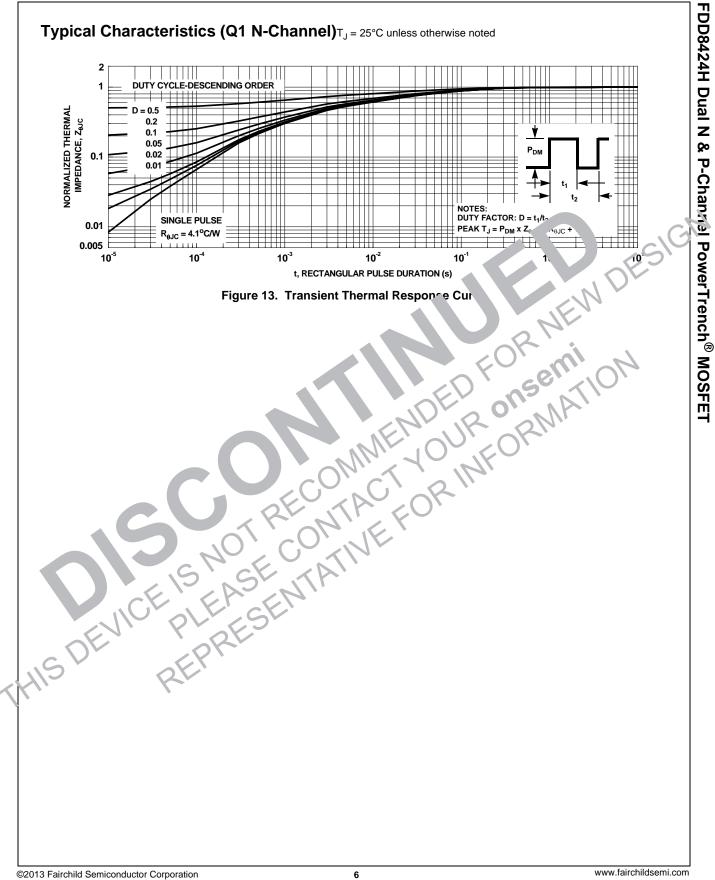
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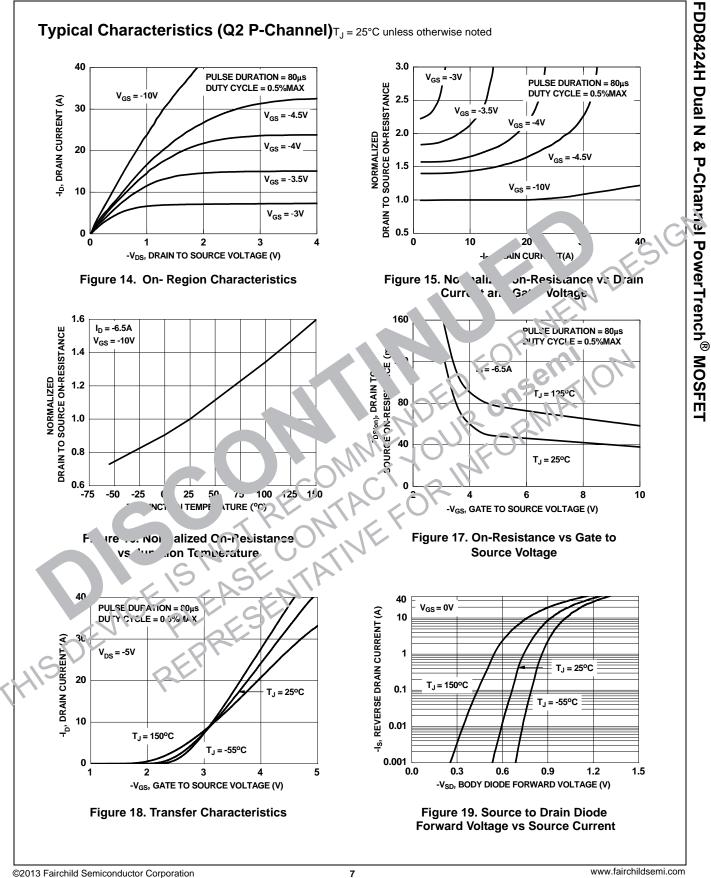


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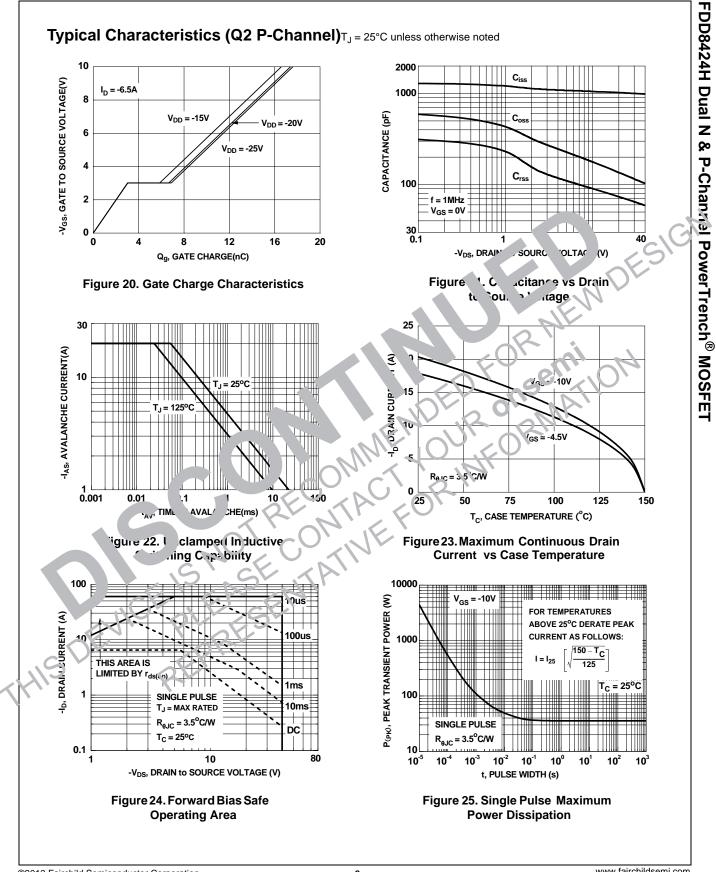
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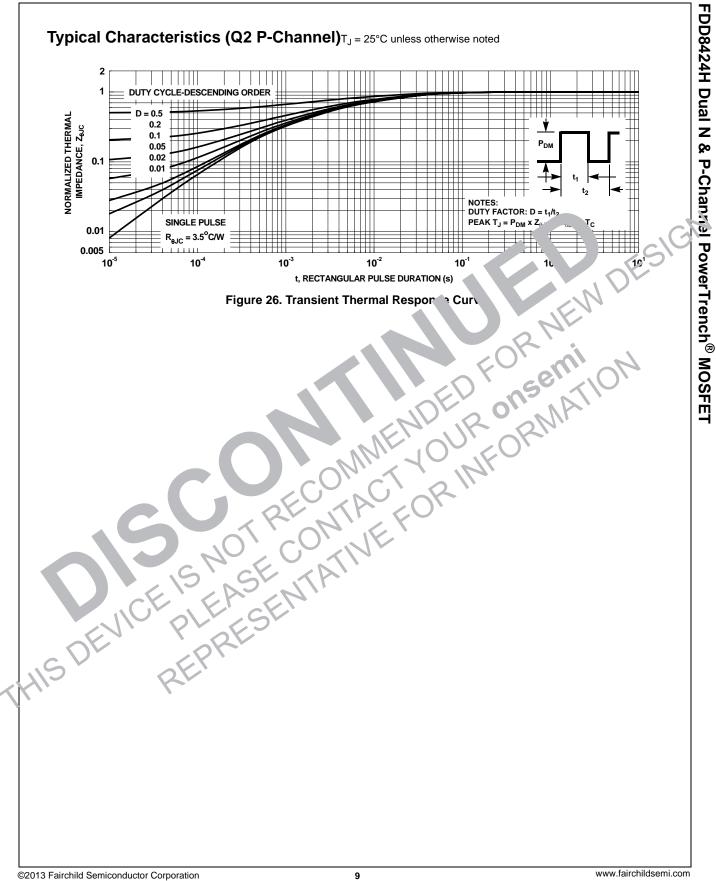


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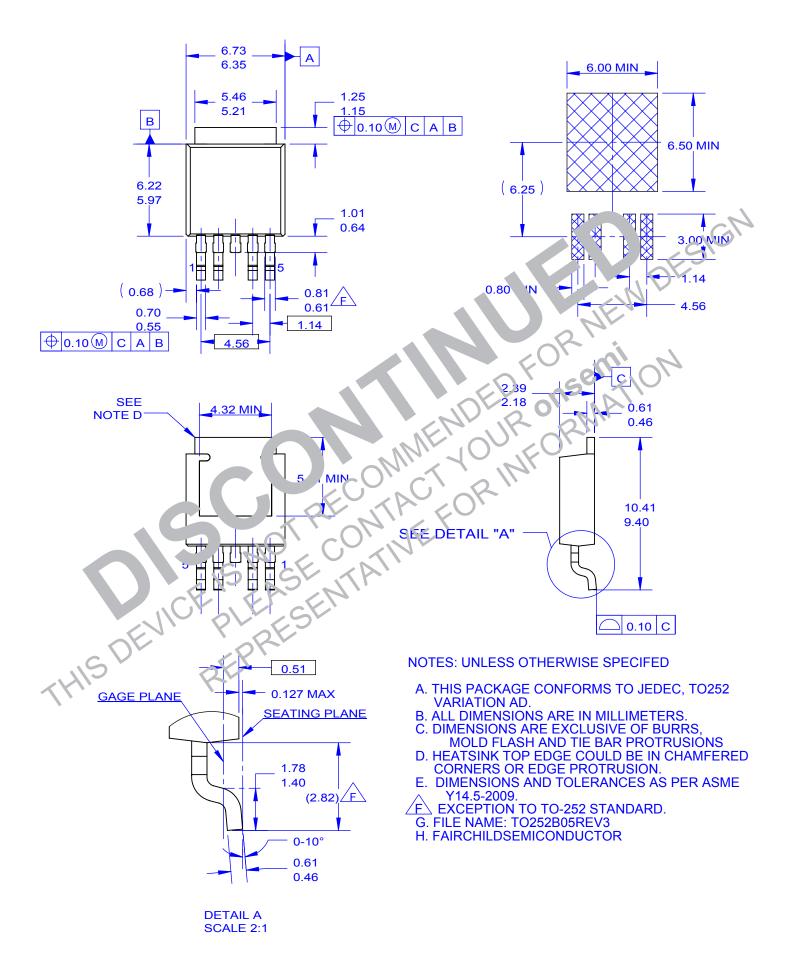
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